

NX2301P 20 V, 2 A P-channel Trench MOSFET Rev. 1 — 26 October 2010

Product data sheet

1. Product profile

1.1 General description

P-channel enhancement mode Field-Effect Transistor (FET) in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

1.2 Features and benefits

- 1.8 V R_{DSon} rated for Low Voltage Gate Drive
- Very fast switching
- Trench MOSFET technology
- AEC-Q101 qualified

1.3 Applications

- Relay driver
- High-speed line driver
- High-side loadswitch
- Switching circuits

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
V _{DS}	drain-source voltage	$T_{amb} = 25 \ ^{\circ}C$	-	-	-20	V
V _{GS}	gate-source voltage	$T_{amb} = 25 \ ^{\circ}C$	-	-	±8	V
I _D	drain current	$T_{amb} = 25 \text{ °C};$ $V_{GS} = -4.5 \text{ V}$	<u>[1]</u> -	-	-2	А
R _{DSon}	drain-source on-state resistance	T _j = 25 °C; V _{GS} = -4.5 V; I _D = -1 A	<u>[2]</u> _	100	120	mΩ

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm², t \leq 5 s.

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2. Pinning information

Table 2.	Pinning			
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate		5
2	S	source		
3	D	drain	1 2	G
				017aaa094

3. Ordering information

Table 3. Ord	Table 3. Ordering information				
Type number	Package				
	Name	Description	Version		
NX2301P	TO-236AB	plastic surface-mounted package; 3 leads	SOT23		

4. Marking

Table 4. Marking codes	
Type number	Marking code ^[1]
NX2301P	MG*

[1] * = placeholder for manufacturing site code

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DS}	drain-source voltage	T _{amb} = 25 °C	-	-20	V
V_{GS}	gate-source voltage	T _{amb} = 25 °C	-	±8	V
I _D	drain current	$V_{GS} = -4.5 V$	<u>[1]</u>		
		T _{amb} = 25 °C	-	-2	А
		$T_{amb} = 100 \ ^{\circ}C$	-	-1.2	А
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; t _p ≤ 10 µs	-	-6	А

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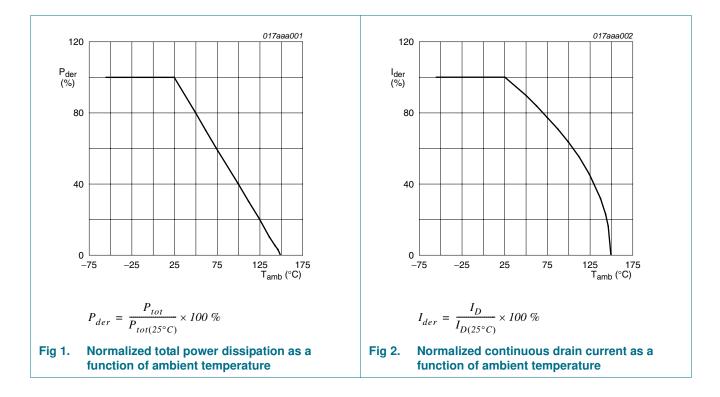
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Symbol	Parameter	Conditions	Min	Max	Unit
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2] _	400	mW
			[1] -	710	mW
		T _{sp} = 25 °C	-	2.8	W
Tj	junction temperature			150	°C
T _{amb}	ambient temperature		-55	+150	°C
T _{stg}	storage temperature		-65	+150	°C
Source-d	rain diode				
I _S	source current	T _{amb} = 25 °C	<u>[1]</u> _	-0.7	Α

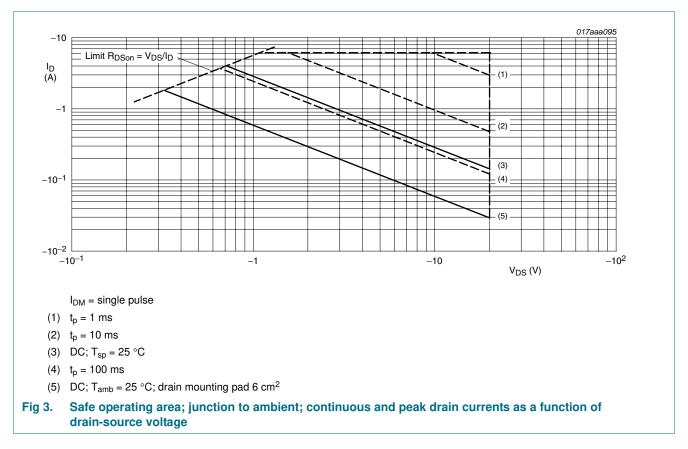
 Table 5.
 Limiting values ...continued

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm², $t \le 5$ s.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.



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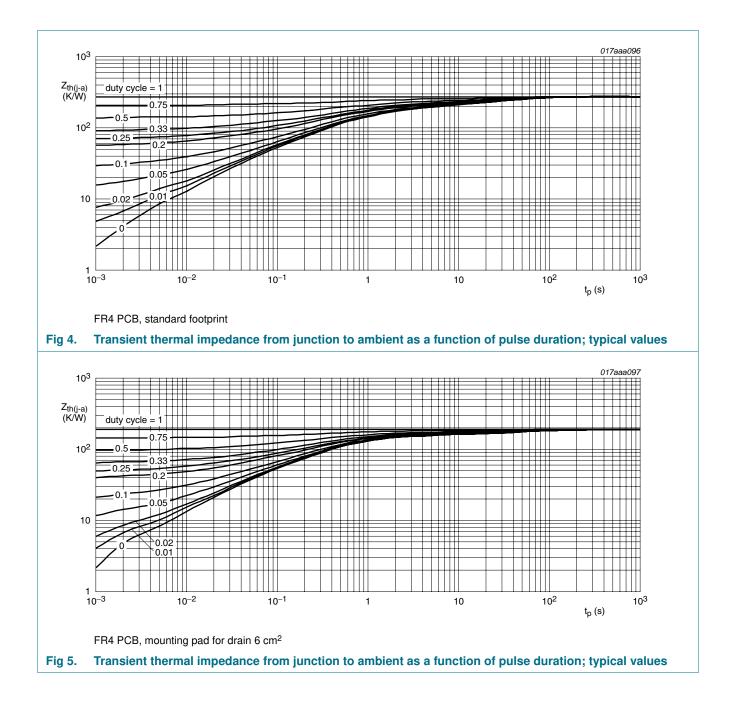
6. Thermal characteristics

Table 6.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from	in free air	<u>[1]</u> -	-	315	K/W
	junction to ambient		[2] _	-	175	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point		-	-	45	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm², t \leq 5 s.

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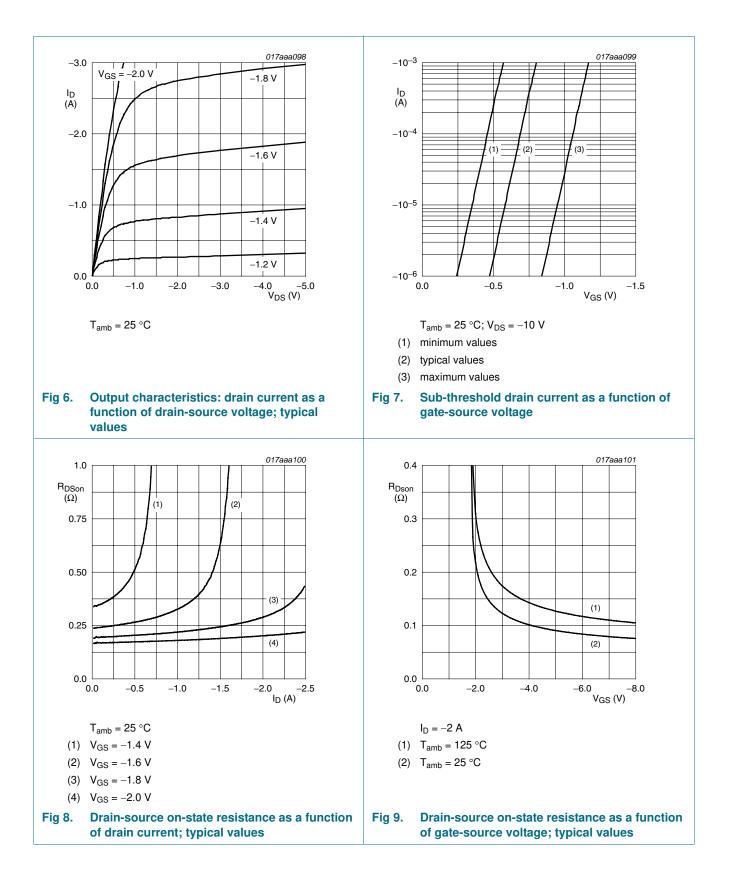
7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
V _{(BR)DSS}	drain-source breakdown voltage	$I_D = -250 \ \mu\text{A}; \ V_{GS} = 0 \ V$	-20	-	-	V
V _{GS(th)}	gate-source threshold voltage	$I_D = -250 \ \mu\text{A}; \ V_{DS} = V_{GS}$	-0.5	-0.75	-1.1	V
I _{DSS}	drain leakage current	$V_{DS} = -20 \text{ V}; V_{GS} = 0 \text{ V}$	-	-	-1	μA
I _{GSS}	gate leakage current	$V_{GS} = \pm 8 \text{ V}; V_{DS} = 0 \text{ V}$	-	-	±100	nA
R _{DSon}	drain-source on-state		<u>[1]</u>			
	resistance	V_{GS} = -4.5 V; I _D = -1 A				
		T _j = 25 °C		100	120	mΩ
		T _j = 150 °C		-	180	mΩ
		V_{GS} = -2.5 V; I _D = -1 A	-	155	190	mΩ
		$V_{GS} = -1.8 \text{ V};$ $I_D = -0.2 \text{ A}$	-	210	270	mΩ
9 _{fs}	forward transconductance	$V_{DS} = -5 \ V; \ I_D = -2 \ A$	<u>[1]</u> -	4.7	-	S
Dynamic of	characteristics					
Q _{G(tot)}	total gate charge	$I_D = -2.2 \text{ A}; V_{DS} = -6 \text{ V};$	-	4.5	6	nC
Q _{GS}	gate-source charge	V _{GS} = -4.5 V	-	1.1	-	nC
Q _{GD}	gate-drain charge		-	0.9	-	nC
C _{iss}	input capacitance	$V_{GS} = 0 V; V_{DS} = -6 V;$	-	380	-	pF
C _{oss}	output capacitance	f = 1 MHz	-	135	-	pF
C _{rss}	reverse transfer capacitance		-	115	-	pF
t _{d(on)}	turn-on delay time	$V_{DD} = -6 V;$	-	7	-	ns
t _r	rise time	$R_L = 6 \Omega;$	-	15	-	ns
t _{d(off)}	turn-off delay time	$-V_{GS} = -4.5 \text{ V};$ $R_G = 6 \Omega$	-	50	-	ns
t _f	fall time		-	25	-	ns
Source-dr	ain diode					
V _{SD}	source-drain voltage	I _S = -1 A; V _{GS} = 0 V	[1] -	-0.8	-1.0	V

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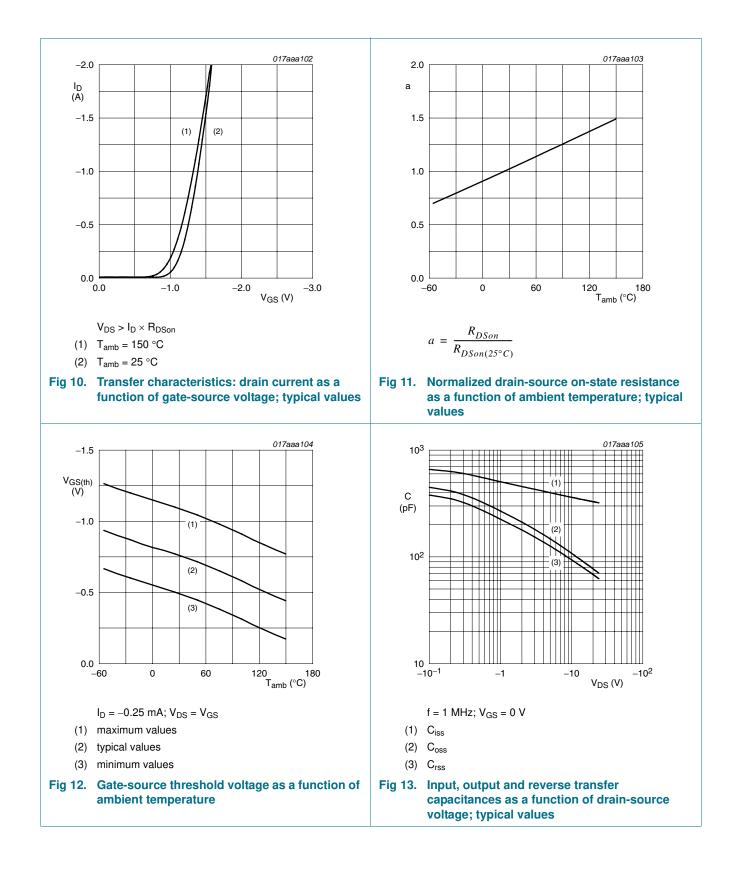
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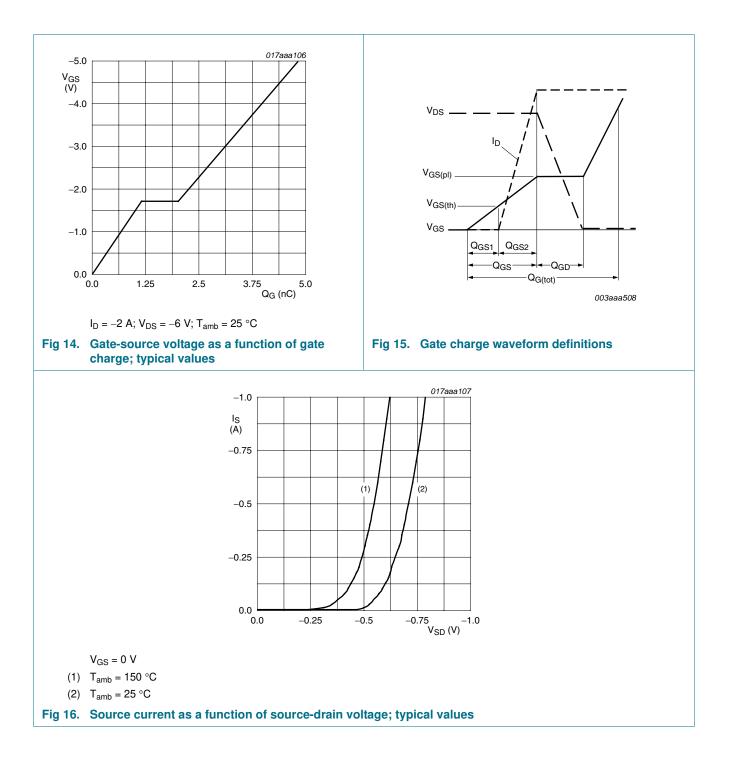
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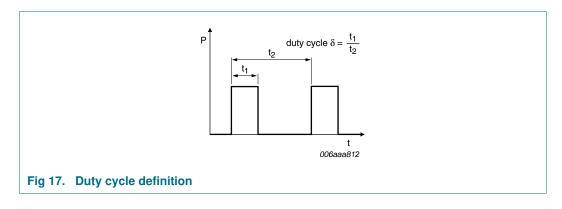


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8. Test information



8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

9. Package outline

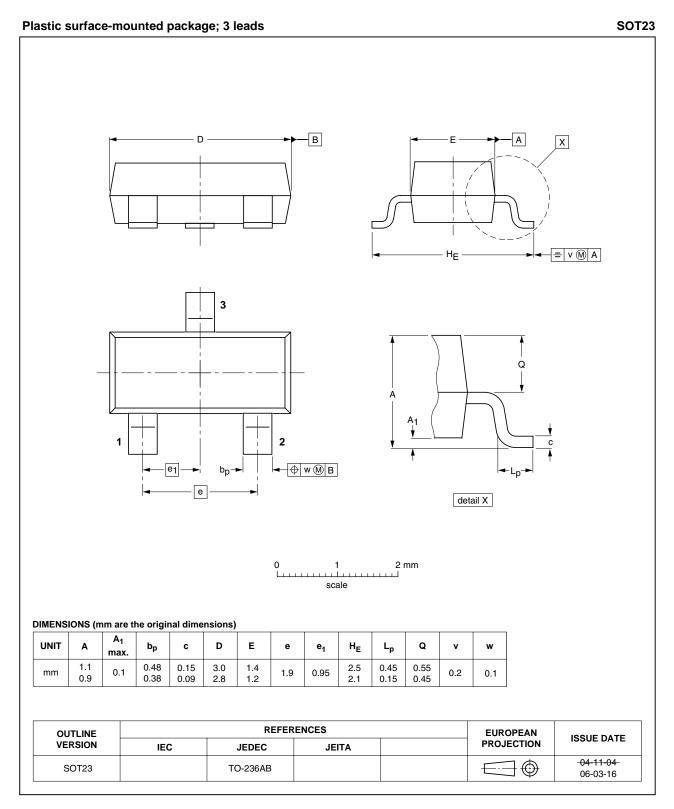
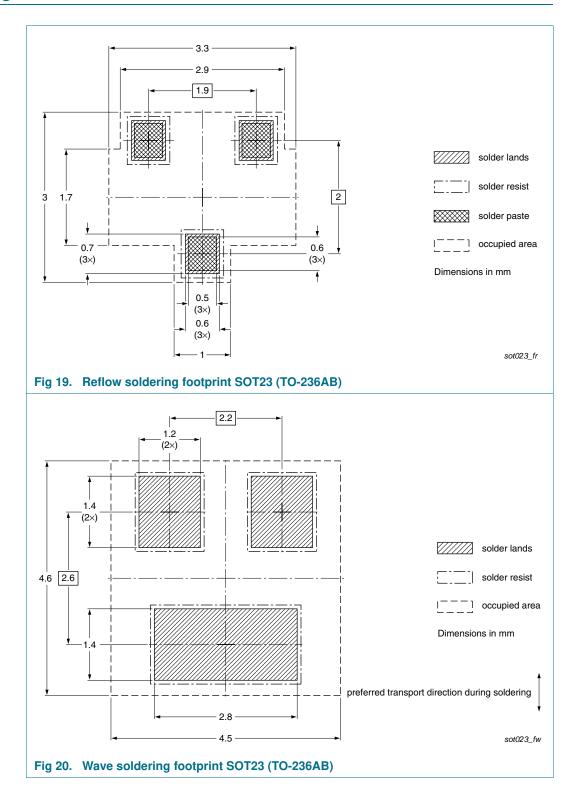


Fig 18. Package outline SOT23 (TO-236AB)

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10. Soldering



11. Revision history

Table 8. Revision	Revision history					
Document ID	Release date	Data sheet status	Change notice	Supersedes		
NX2301P v.1	20101026	Product data sheet	-	-		

12. Legal information

12.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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